

Voltage Output, High or Low Side Measurement, Bi-Directional Zero-Drift Series CURRENT SHUNT MONITOR

FEATURES

- **WIDE COMMON-MODE RANGE:** -0.3V to 26V
- **OFFSET VOLTAGE:** $\pm 35\mu\text{V}$ (Max, INA210)
(Enables shunt drops of 10mV full-scale)
- **ACCURACY**
 - $\pm 1\%$ Gain Error (Max over temperature)
 - $0.5\mu\text{V}/^\circ\text{C}$ Offset Drift (Max)
 - $10\text{ppm}/^\circ\text{C}$ Gain Drift (Max)
- **CHOICE OF GAINS:**
 - **INA210:** 200V/V
 - **INA211:** 500V/V
 - **INA212:** 1000V/V
 - **INA213:** 50V/V
 - **INA214:** 100V/V
- **QUIESCENT CURRENT:** $100\mu\text{A}$ (max)
- **SC70 PACKAGE:** All Models
- **THIN QFN PACKAGE:** INA210, INA213, INA214

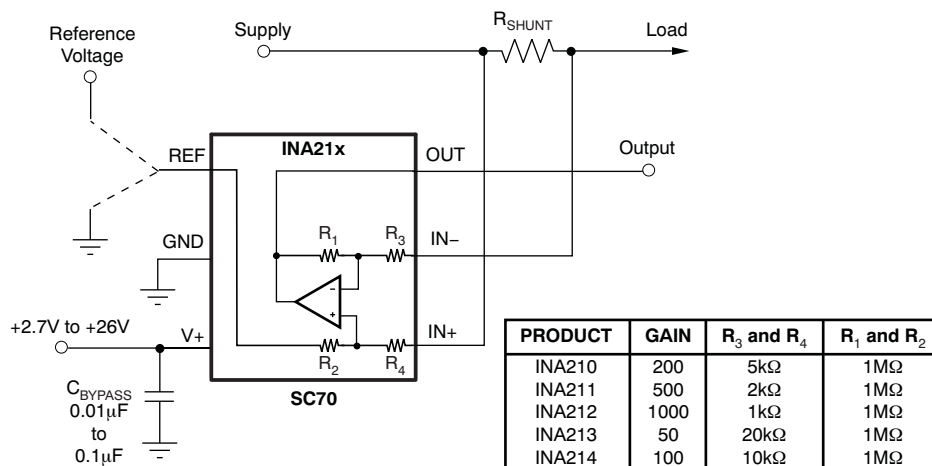
APPLICATIONS

- NOTEBOOK COMPUTERS
- CELL PHONES
- TELECOM EQUIPMENT
- POWER MANAGEMENT
- BATTERY CHARGERS
- WELDING EQUIPMENT

DESCRIPTION

The INA210, INA211, INA212, INA213, and INA214 are voltage output current shunt monitors that can sense drops across shunts at common-mode voltages from -0.3V to 26V , independent of the supply voltage. Five fixed gains are available: 50V/V , 100V/V , 200V/V , 500V/V , or 1000V/V . The low offset of the Zero-Drift architecture enables current sensing with maximum drops across the shunt as low as 10mV full-scale.

These devices operate from a single $+2.7\text{V}$ to $+26\text{V}$ power supply, drawing a maximum of $100\mu\text{A}$ of supply current. All versions are specified over the extended operating temperature range (-40°C to $+125^\circ\text{C}$), and offered in an SC70 package. The INA210, INA213, and INA214 are also offered in a thin QFN package.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION⁽¹⁾

PRODUCT	GAIN	PACKAGE	PACKAGE DESIGNATOR	PACKAGE MARKING
INA210	200V/V	SC70-6	DCK	CET
INA210	200V/V	Thin QFN-10	RSW	KNJ
INA211	500V/V	SC70-6	DCK	CEU
INA212	1000V/V	SC70-6	DCK	CEV
INA213	50V/V	SC70-6	DCK	CFT
INA213	50V/V	Thin QFN-10	RSW	KPJ
INA214	100V/V	SC70-6	DCK	CFV
INA214	100V/V	Thin QFN-10	RSW	KRJ

(1) For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet, or refer to our web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Over operating free-air temperature range, unless otherwise noted.

		INA210, INA211, INA212, INA213, INA214	UNIT
Supply Voltage		+26	V
Analog Inputs, V_{IN+} , V_{IN-} ⁽²⁾	Differential (V_{IN+})–(V_{IN-})	–26 to +26	V
	Common-Mode ⁽³⁾	GND–0.3 to +26	V
REF Input		GND–0.3 to ($V+$) + 0.3	V
Output ⁽³⁾		GND–0.3 to ($V+$) + 0.3	V
Input Current into Any Pin ⁽³⁾		5	mA
Operating Temperature		–55 to +150	°C
Storage Temperature		–65 to +150	°C
Junction Temperature		+150	°C
ESD Ratings:	Human Body Model (HBM)	4000	V
	Charged-Device Model (CDM)	1000	V
	Machine Model (MM)	200	V

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) V_{IN+} and V_{IN-} are the voltages at the IN+ and IN– pins, respectively.

(3) Input Voltage at any pin may exceed the voltage shown if the current at that pin is limited to 5mA.

ELECTRICAL CHARACTERISTICS

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$.

At $T_A = +25^{\circ}\text{C}$, $V_{\text{SENSE}} = V_{\text{IN}+} - V_{\text{IN}-}$.

INA210, INA213 and INA214: $V_S = +5\text{V}$, $V_{\text{IN}+} = 12\text{V}$, and $V_{\text{REF}} = V_S/2$, unless otherwise noted.

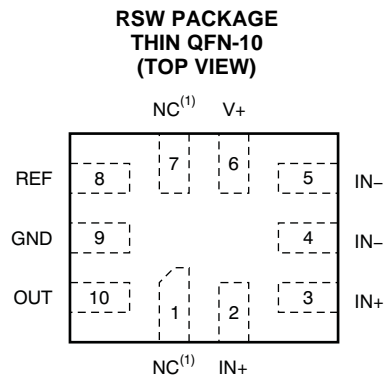
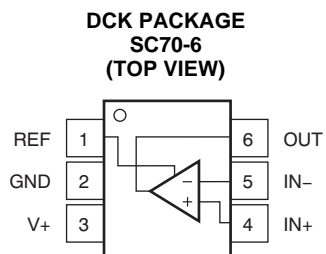
INA211 and INA212: $V_S = +12\text{V}$, $V_{\text{IN}+} = 12\text{V}$, and $V_{\text{REF}} = V_S/2$, unless otherwise noted.

PARAMETER	CONDITIONS	INA210, INA211, INA212, INA213, INA214			UNIT
		MIN	TYP	MAX	
INPUT					
Common-Mode Input Range V_{CM}		-0.3		26	V
Common-Mode Rejection CMR	$V_{\text{IN}+} = 0\text{V}$ to $+26\text{V}$, $V_{\text{SENSE}} = 0\text{mV}$				
INA210, INA211, INA212, INA214		105	140		dB
INA213		100	120		dB
Offset Voltage, $\text{RTI}^{(1)}$ V_{OS}	$V_{\text{SENSE}} = 0\text{mV}$				
INA210, INA211, INA212			± 0.55	± 35	μV
INA213			± 5	± 100	μV
INA214			± 1	± 60	μV
vs Temperature $\text{d}V_{\text{OS}}/\text{d}T$			0.1	0.5	$\mu\text{V}/^{\circ}\text{C}$
vs Power Supply PSR	$V_S = +2.7\text{V}$ to $+18\text{V}$, $V_{\text{IN}+} = +18\text{V}$, $V_{\text{SENSE}} = 0\text{mV}$		± 0.1	± 10	$\mu\text{V}/\text{V}$
Input Bias Current I_{B}	$V_{\text{SENSE}} = 0\text{mV}$	15	28	35	μA
Input Offset Current I_{OS}	$V_{\text{SENSE}} = 0\text{mV}$		± 0.02		μA
OUTPUT					
Gain, INA210 G			200		V/V
INA211			500		V/V
INA212			1000		V/V
INA213			50		V/V
INA214			100		V/V
Gain Error $V_{\text{SENSE}} = -5\text{mV}$ to 5mV			± 0.02	± 1	%
vs Temperature			3	10	ppm/$^{\circ}\text{C}$
Nonlinearity Error $V_{\text{SENSE}} = -5\text{mV}$ to 5mV			± 0.01		%
Maximum Capacitive Load No sustained oscillation			1		nF
VOLTAGE OUTPUT⁽²⁾	$R_L = 10\text{k}\Omega$ to GND				
Swing to V_+ Power-Supply Rail			$(V_+) - 0.05$	$(V_+) - 0.2$	V
Swing to GND			$(V_{\text{GND}}) + 0.005$	$(V_{\text{GND}}) + 0.05$	V
FREQUENCY RESPONSE					
Bandwidth GBW	$C_{\text{LOAD}} = 10\text{pF}$		14		kHz
Slew Rate SR			0.4		$\text{V}/\mu\text{s}$
NOISE, $\text{RTI}^{(1)}$					
Voltage Noise Density			25		$\text{nV}/\sqrt{\text{Hz}}$
POWER SUPPLY					
Operating Voltage Range V_S		+2.7		+26	V
Quiescent Current I_{Q}	$V_{\text{SENSE}} = 0\text{mV}$		65	100	μA
Over Temperature				115	μA
TEMPERATURE RANGE					
Specified Range		-40		+125	$^{\circ}\text{C}$
Operating Range		-55		+150	$^{\circ}\text{C}$
Thermal Resistance θ_{JA}					
SC70			250		$^{\circ}\text{C}/\text{W}$
Thin QFN			80		$^{\circ}\text{C}/\text{W}$

(1) RTI = referred-to-input.

(2) See Typical Characteristic curve, *Output Voltage Swing vs Output Current* (Figure 10).

PIN CONFIGURATIONS



(1) NC denotes no internal connection. Pin can be left floating or connected to any voltage between V^- and V^+ .

TYPICAL CHARACTERISTICS

The INA210 is used for typical characteristics at $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, $V_{IN+} = 12\text{V}$, and $V_{REF} = V_S/2$, unless otherwise noted.

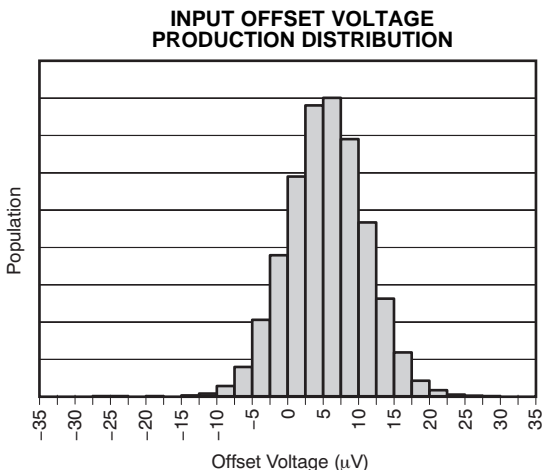


Figure 1.

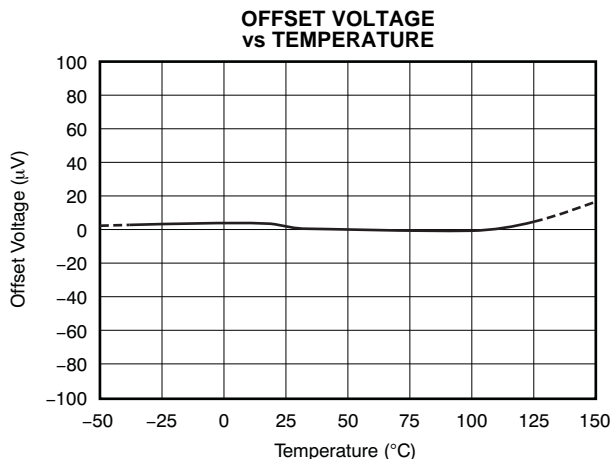


Figure 2.

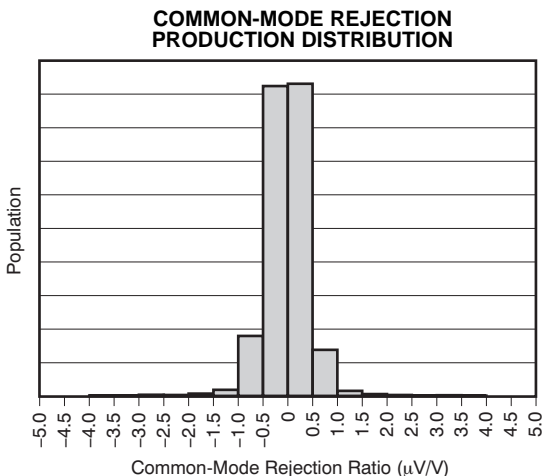


Figure 3.

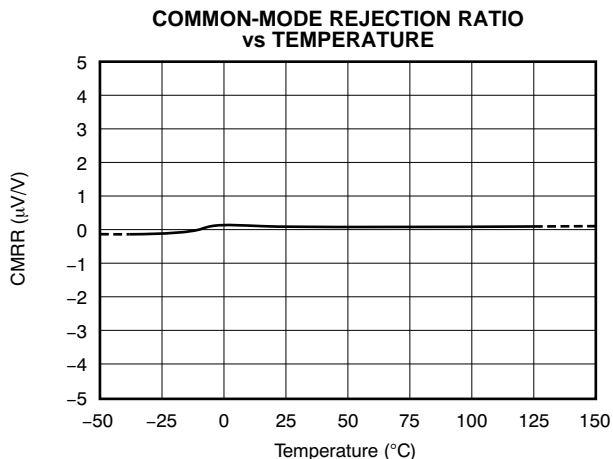


Figure 4.

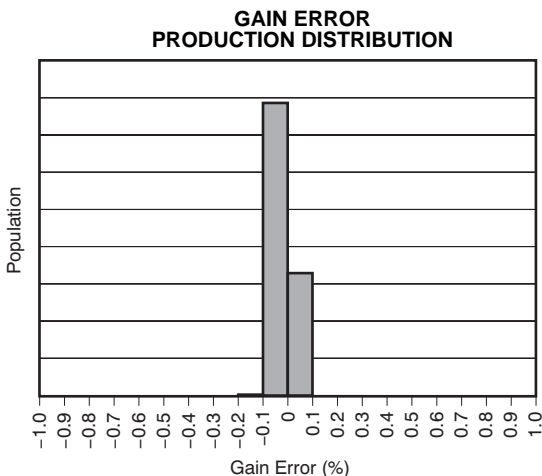


Figure 5.

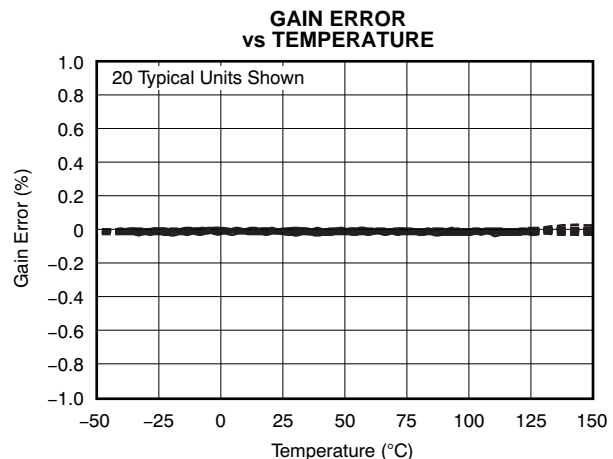


Figure 6.

TYPICAL CHARACTERISTICS (continued)

The INA210 is used for typical characteristics at $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, $V_{IN+} = 12\text{V}$, and $V_{REF} = V_S/2$, unless otherwise noted.

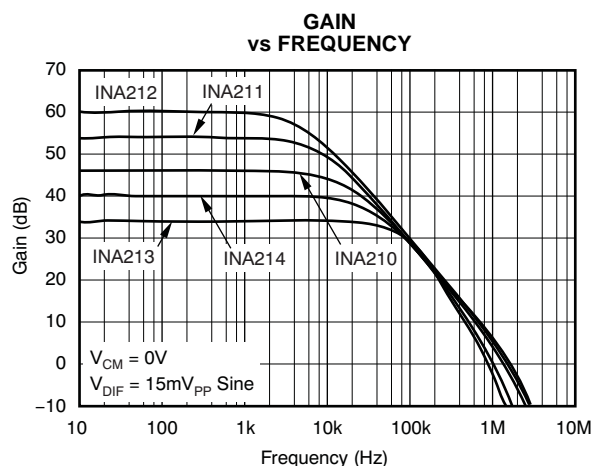


Figure 7.

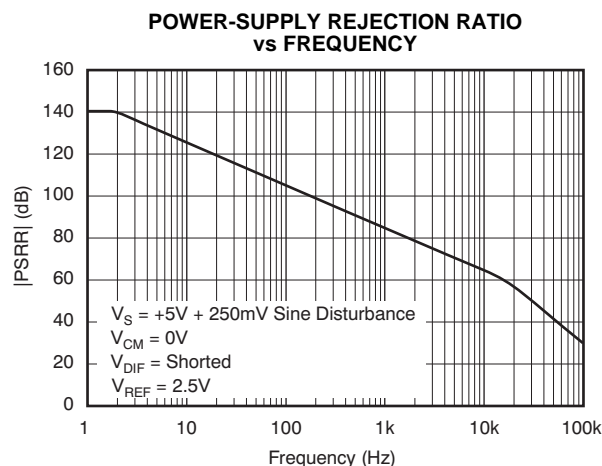


Figure 8.

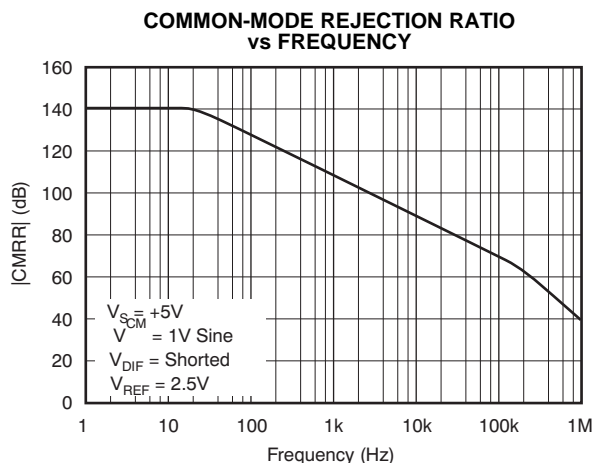


Figure 9.

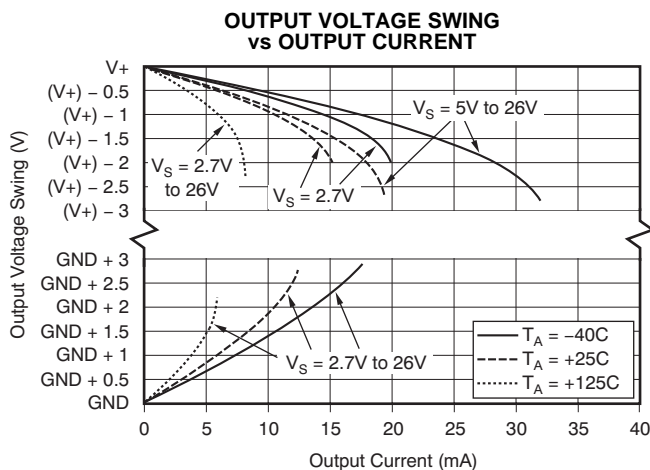


Figure 10.

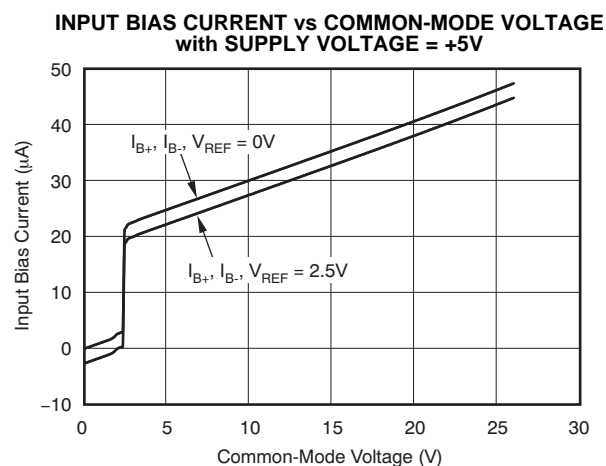


Figure 11.

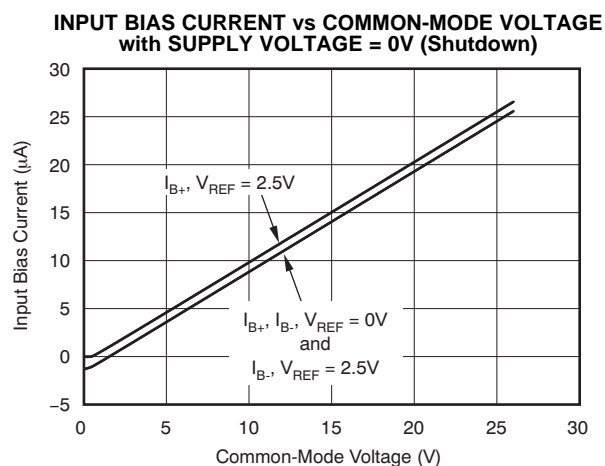


Figure 12.

TYPICAL CHARACTERISTICS (continued)

The INA210 is used for typical characteristics at $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, $V_{IN+} = 12\text{V}$, and $V_{REF} = V_S/2$, unless otherwise noted.

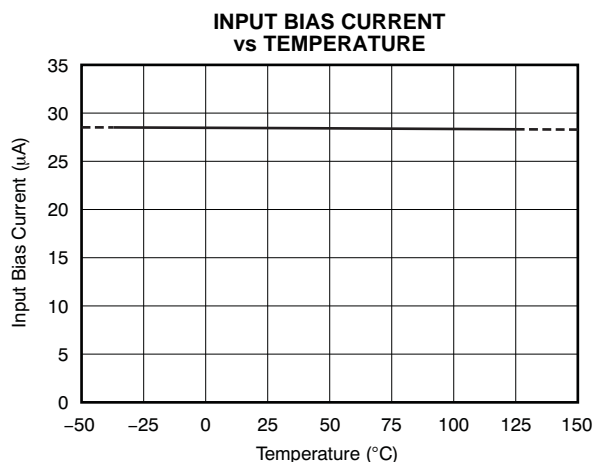


Figure 13.

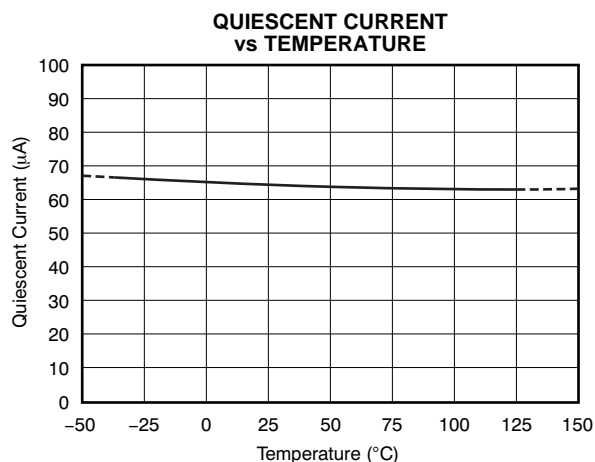


Figure 14.

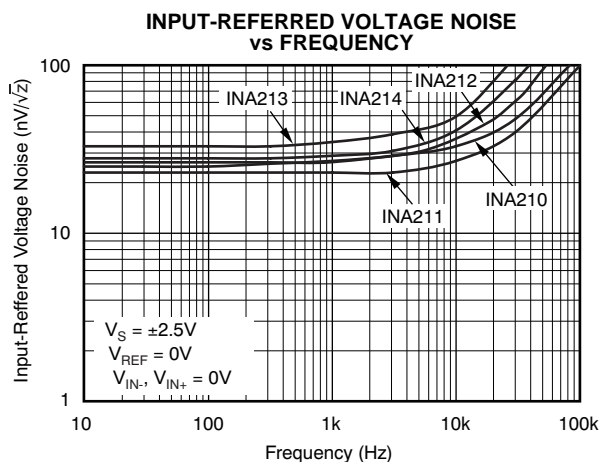


Figure 15.

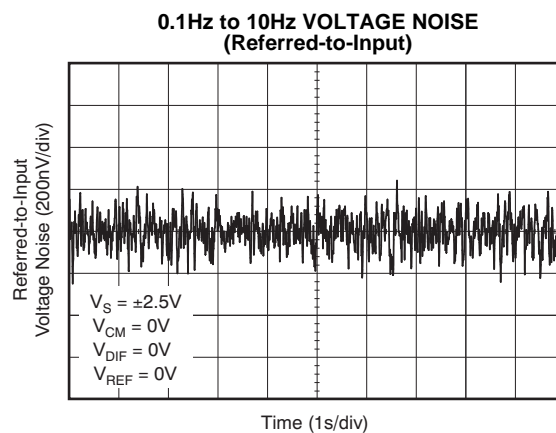


Figure 16.

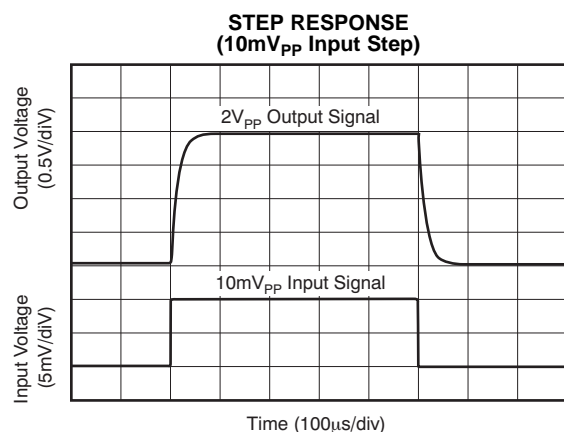


Figure 17.

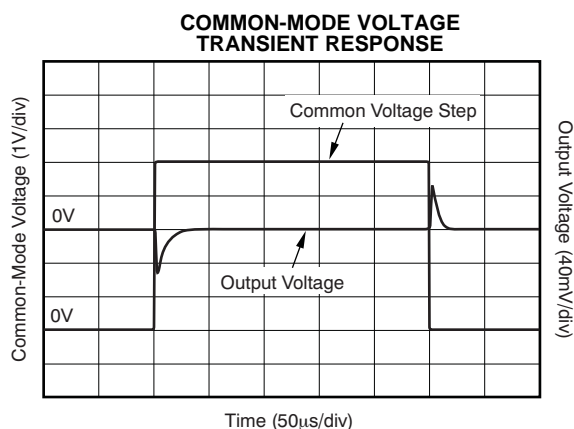


Figure 18.

TYPICAL CHARACTERISTICS (continued)

The INA210 is used for typical characteristics at $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, $V_{IN+} = 12\text{V}$, and $V_{REF} = V_S/2$, unless otherwise noted.

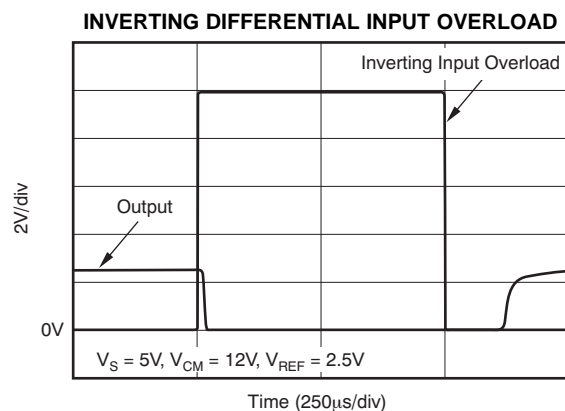


Figure 19.

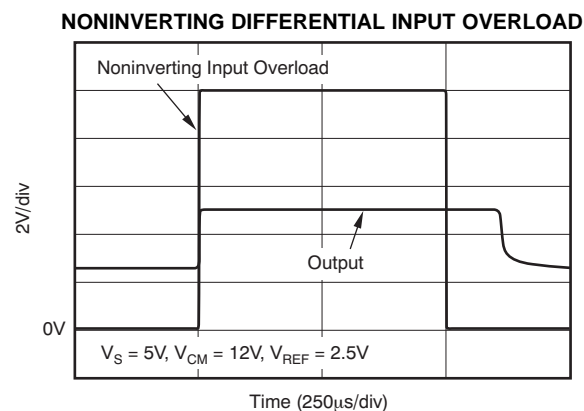


Figure 20.

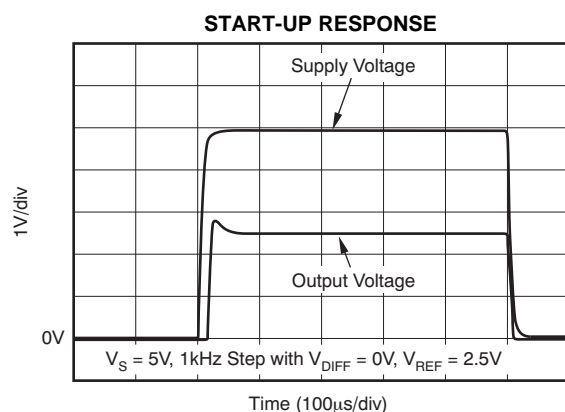


Figure 21.

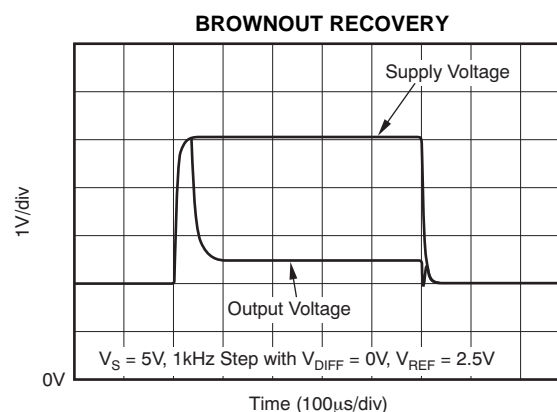


Figure 22.

APPLICATION INFORMATION

BASIC CONNECTIONS

Figure 23 shows the basic connections of the INA210-INA214. The input pins, IN+ and IN–, should be connected as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistance.

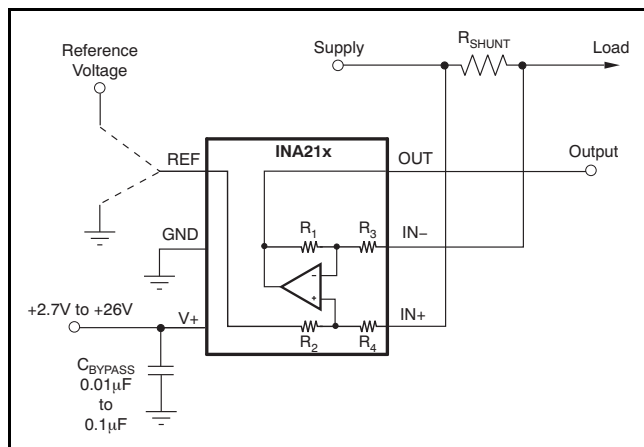


Figure 23. Typical Application

Power-supply bypass capacitors are required for stability. Applications with noisy or high impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

On the RSW package, two pins are provided for each input. These pins should be tied together (that is, tie IN+ to IN+ and tie IN– to IN–).

POWER SUPPLY

The input circuitry of the INA210-INA214 can accurately measure beyond its power-supply voltage, V+. For example, the V+ power supply can be 5V, whereas the load power supply voltage can be as high as +26V. However, the output voltage range of the OUT terminal is limited by the voltages on the power-supply pin. Note also that the INA210-INA214 can withstand the full –0.3V to +26V in the input pins, regardless of whether the device has power applied or not.

SELECTING R_s

The zero-drift offset performance of the INA210-INA214 offers several benefits. Most often, the primary advantage of the low offset characteristic enables lower full-scale drops across the shunt. For example, non-zero-drift current shunt monitors typically require a full-scale range of 100mV.

The INA210-INA214 series gives equivalent accuracy at a full-scale range on the order of 10mV. This accuracy reduces shunt dissipation by an order of magnitude with many additional benefits.

Alternatively, there are applications that must measure current over a wide dynamic range that can take advantage of the low offset on the low end of the measurement. Most often, these applications can use the lower gain INA213 or INA214 to accommodate larger shunt drops on the upper end of the scale. For instance, an INA213 operating on a 3.3V supply could easily handle a full-scale shunt drop of 60mV, with only 100 μ V of offset.

UNIDIRECTIONAL OPERATION

Unidirectional operation allows the INA210-INA214 to measure currents through a resistive shunt in one direction. The most frequent case of unidirectional operation sets the output at ground by connecting the REF pin to ground. In unidirectional applications where the highest possible accuracy is desirable at very low inputs, bias the REF pin to a convenient value above 50mV to get the device output swing into the linear range for zero inputs.

A less frequent case of unipolar output biasing is to bias the output by connecting the REF pin to the supply; in this case, the quiescent output for zero input is at quiescent supply. This configuration would only respond to negative currents (inverted voltage polarity at the device input).

BIDIRECTIONAL OPERATION

Bidirectional operation allows the INA210-INA214 to measure currents through a resistive shunt in two directions. In this case, the output can be set anywhere within the limits of what the reference inputs allow (that is, between 0V to V+). Typically, it is set at half-scale for equal range in both directions. In some cases, however, it is set at a voltage other than half-scale when the bidirectional current is nonsymmetrical.

The quiescent output voltage is set by applying voltage to the reference input. Under zero differential input conditions the output assumes the same voltage as is applied to the reference input.

INPUT FILTERING

An obvious and straightforward location for filtering is at the output of the INA210-INA214; however, this location negates the advantage of the low output impedance of the internal buffer. The only other option for filtering is at the input pins of the INA210-INA214; this location requires consideration of the $\pm 30\%$ tolerance of the input impedance. [Figure 24](#) shows a filter placed at the input pins.

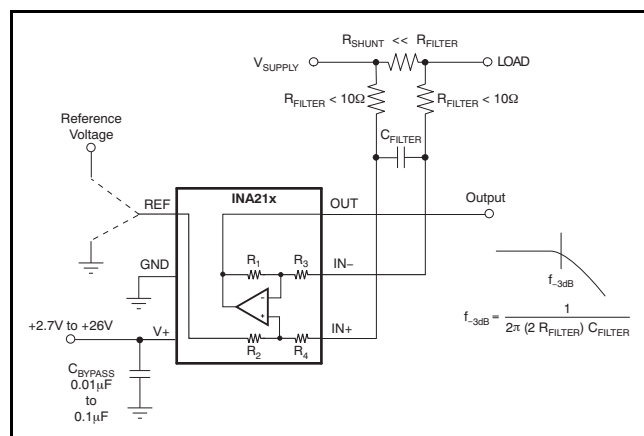


Figure 24. Input Filter

Using the lowest possible resistor values minimizes both the initial shift in gain and effects of tolerance. The effect on initial gain is given by [Equation 1](#):

$$\text{GainError\%} = 100 - [100 \times \{R/(R + R_{\text{FILT}})\}] \quad (1)$$

Where R is the value for R_3 or R_4 from Table 1 for the model is in question.

Table 1.

PRODUCT	GAIN	R ₃ AND R ₄
INA210	200	5kΩ
INA211	500	2kΩ
INA212	1000	1kΩ
INA213	50	20kΩ
INA214	100	10kΩ

Using an INA212, for example, the total effect on gain error can be calculated by replacing the R with $1k\Omega - 30\%$, (or 700Ω) or $1k\Omega + 30\%$ (or $1.3k\Omega$). The tolerance extremes of R_{FILT} can also be inserted into the equation. If a pair of 100Ω , 1% resistors are used on the inputs, the initial gain error is approximately 2%.

SHUTTING DOWN THE INA210-INA214 SERIES

While the INA210-INA214 series does not have a shutdown pin, its low power consumption allows powering from the output of a logic gate or transistor switch that can turn on and turn off the INA210-INA214 power-supply quiescent current.

However, in current shunt monitoring applications, there is also a concern for how much current is drained from the shunt circuit in shutdown conditions. Evaluating this current drain involves considering the simplified schematic of the INA210-INA214 in shutdown mode shown in [Figure 25](#).

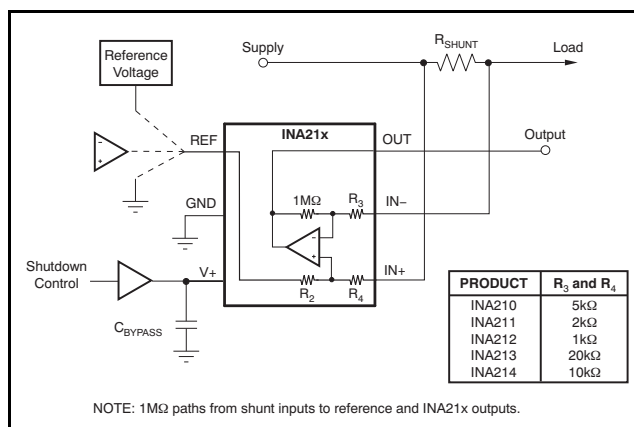


Figure 25. Basic Circuit for Shutting Down INA210-INA214 with Grounded Reference

Note that there is typically slightly more than $1\text{M}\Omega$ impedance (from the combination of $1\text{M}\Omega$ feedback and $5\text{k}\Omega$ input resistors) from each input of the INA210-INA214 to the OUT pin and to the REF pin. The amount of current flowing through these pins depends on the respective ultimate connection. For example, if the REF pin is grounded, the calculation of the effect of the $1\text{M}\Omega$ impedance from the shunt to ground is straightforward. However, if the reference or op amp is powered while the INA210-INA214 is shut down, the calculation is direct; instead of assuming $1\text{M}\Omega$ to ground, however, assume $1\text{M}\Omega$ to the reference voltage. If the reference or op amp is also shut down, some knowledge of the reference or op amp output impedance under shutdown conditions is required. For instance, if the reference source behaves as an open circuit when it is unpowered, little or no current flows through the $1\text{M}\Omega$ path.

Regarding the $1\text{M}\Omega$ path to the output pin, the output stage of a disabled INA210-INA214 does constitute a good path to ground; consequently, this current is directly proportional to a shunt common-mode voltage impressed across a $1\text{M}\Omega$ resistor.

As a final note, when the device is powered up, there is an additional, nearly constant, and well-matched $25\mu\text{A}$ that flows in each of the inputs as long as the shunt common-mode voltage is 3V or higher. Below 2V common-mode, the only current effects are the result of the $1\text{M}\Omega$ resistors.

REF INPUT IMPEDANCE EFFECTS

As with any difference amplifier, the INA210-INA214 series common-mode rejection ratio is affected by any impedance present at the REF input. This concern is not a problem when the REF pin is connected directly to most references or power supplies. When using resistive dividers from the power supply or a reference voltage, the REF pin should be buffered by an op amp.

In systems where the INA210-INA214 output can be sensed differentially, such as by a differential input analog-to-digital converter (ADC) or by using two separate ADC inputs, the effects of external impedance on the REF input can be cancelled. Figure 26 depicts a method of taking the output from the INA210-INA214 by using the REF pin as a reference.

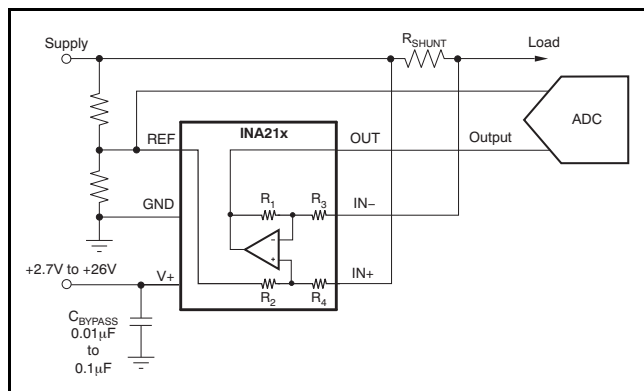


Figure 26. Sensing INA210-INA214 to Cancel Effects of Impedance on the REF Input

USING THE INA210 WITH COMMON-MODE TRANSIENTS ABOVE 26V

With a small amount of additional circuitry, the INA210-INA214 series can be used in circuits subject to transients higher than 26V, such as automotive applications. Use only zener diode or zener-type transient absorbers (sometimes referred to as *Transzorbs*)— any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors as shown in Figure 27 as a working impedance for the zener. It is desirable to keep these resistors as small as possible, most often around 10Ω . Larger values can be used with an effect on gain that is discussed in the section on input filtering. Because this circuit is limiting only short-term transients, many applications are satisfied with a 10Ω resistor along with conventional zener diodes of the lowest power rating that can be found. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523.

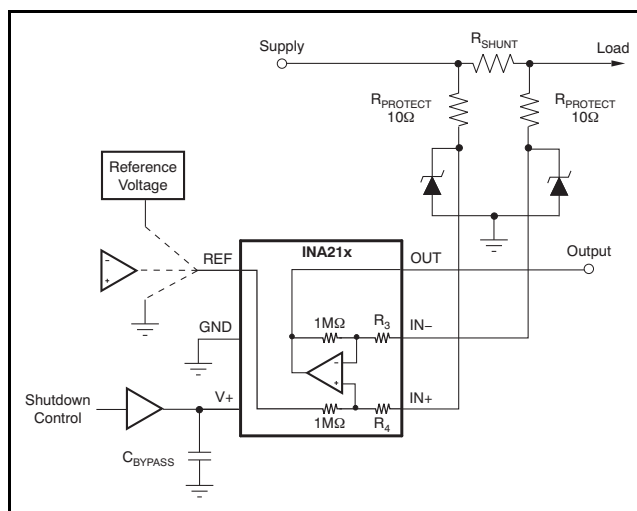


Figure 27. INA210-INA214 Transient Protection Using Dual Zener Diodes

In the event that low-power zeners do not have sufficient transient absorption capability and a higher power transzorb must be used, the most package-efficient solution then involves using a single transzorb and back-to-back diodes between the device inputs. The most space-efficient solutions are dual series-connected diodes in a single SOT-523 or SOD-523 package. This method is shown in [Figure 28](#). In either of these examples, the total board area required by the INA210-INA214 with all protective components is less than that of an SO-8 package, and only slightly greater than that of an MSOP-8 package.

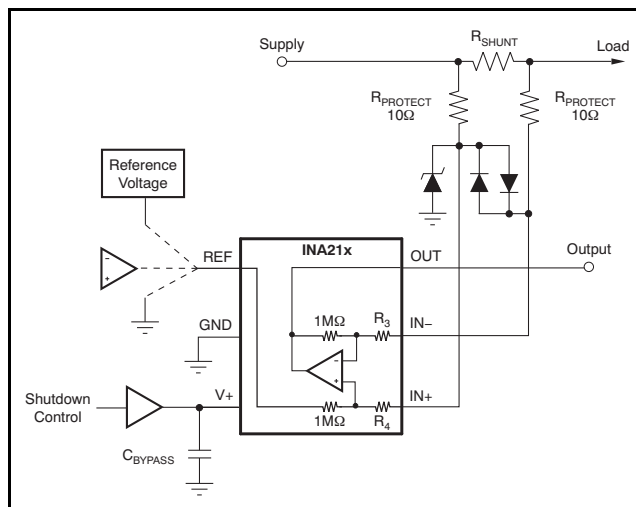


Figure 28. INA210-INA214 Transient Protection Using a Single Transzorb and Input Clamps

Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (June 2008) to Revision B	Page
• Added QFN package to <i>Features</i> list.....	1
• Updated front page graphic	1
• Added RSW package to device photo	1
• Added RSW ordering information to <i>Package/Ordering Information</i> table	2
• Added footnote 3 to <i>Electrical Characteristics</i> table	3
• Added QFN package information to <i>Temperature Range</i> section of <i>Electrical Characteristics</i> table	3
• Added RSW package pin out drawing	4
• Changed Figure 2 to reflect operating temperature range	5
• Changed Figure 4 to reflect operating temperature range	5
• Changed Figure 6 to reflect operating temperature range	5
• Changed Figure 13 to reflect operating temperature range	7
• Changed Figure 14 to reflect operating temperature range	7
• Added RSW description to the Basic Connections section	9
• Changed 60μV to 100μV in last sentence of the Selecting RS section.....	9

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
INA210AIDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA210AIDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA210AIDCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA210AIDCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA210AIRSWR	ACTIVE	UQFN	RSW	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
INA210AIRSWT	ACTIVE	UQFN	RSW	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
INA211AIDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA211AIDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA211AIDCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA211AIDCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA212AIDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA212AIDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA212AIDCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA212AIDCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA213AIDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA213AIDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA213AIDCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
INA213AIDCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA213AIRSWR	ACTIVE	UQFN	RSW	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
INA213AIRSWT	ACTIVE	UQFN	RSW	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
INA214AIDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA214AIDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Purchase Samples
INA214AIDCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA214AIDCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	Request Free Samples
INA214AIRSWR	ACTIVE	UQFN	RSW	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
INA214AIRSWT	ACTIVE	UQFN	RSW	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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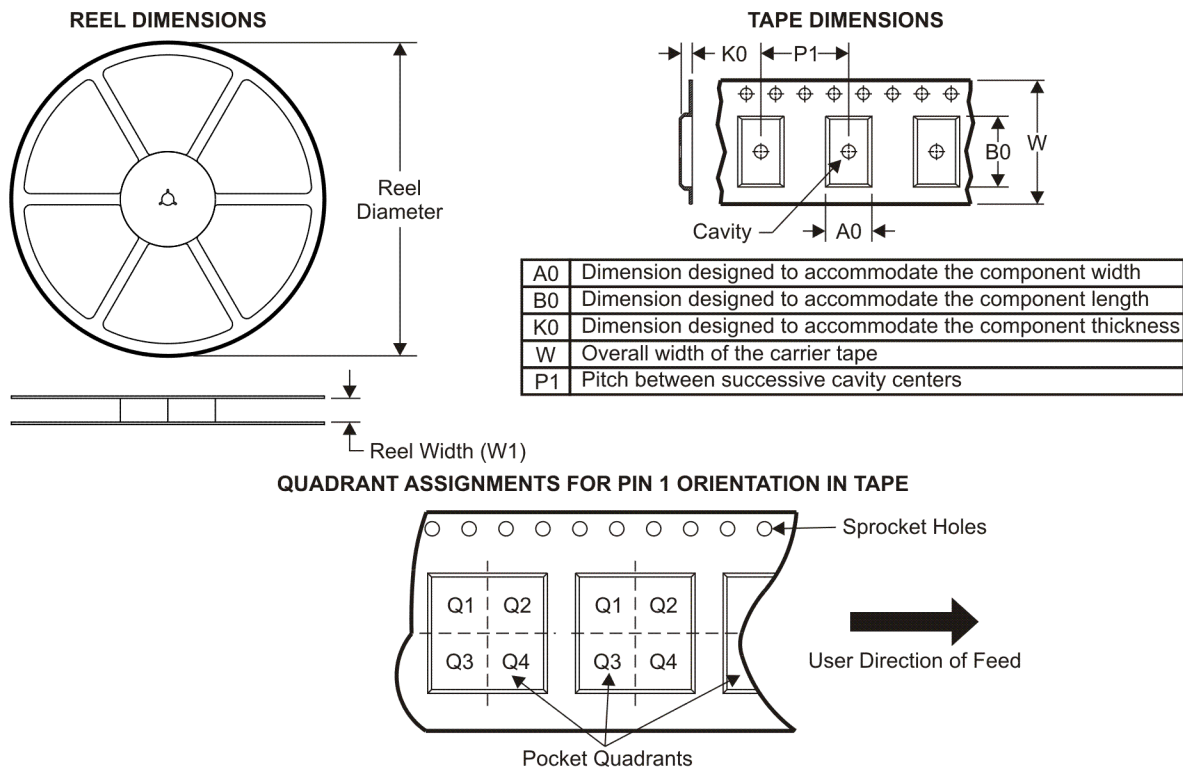
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OTHER QUALIFIED VERSIONS OF INA214 :

- Automotive: [INA214-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA210AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA210AIDCKT	SC70	DCK	6	250	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA210AIRSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA210AIRSWT	UQFN	RSW	10	250	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA211AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA211AIDCKT	SC70	DCK	6	250	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA212AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA212AIDCKT	SC70	DCK	6	250	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA213AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA213AIDCKT	SC70	DCK	6	250	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA213AIRSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA213AIRSWT	UQFN	RSW	10	250	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA214AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA214AIDCKT	SC70	DCK	6	250	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3
INA214AIRSWR	UQFN	RSW	10	3000	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1
INA214AIRSWT	UQFN	RSW	10	250	179.0	8.4	1.7	2.1	0.7	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

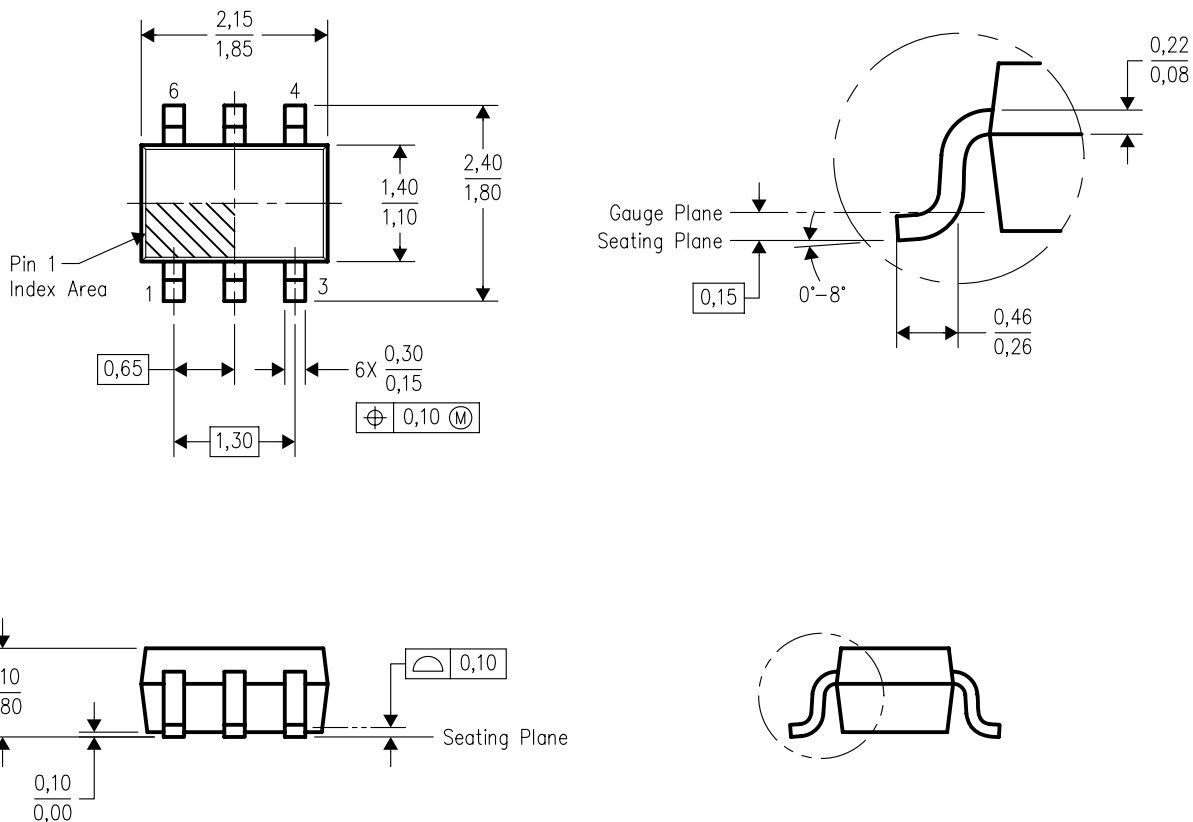


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA210AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
INA210AIDCKT	SC70	DCK	6	250	202.0	201.0	28.0
INA210AIRSWR	UQFN	RSW	10	3000	203.0	203.0	35.0
INA210AIRSWT	UQFN	RSW	10	250	203.0	203.0	35.0
INA211AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
INA211AIDCKT	SC70	DCK	6	250	202.0	201.0	28.0
INA212AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
INA212AIDCKT	SC70	DCK	6	250	202.0	201.0	28.0
INA213AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
INA213AIDCKT	SC70	DCK	6	250	202.0	201.0	28.0
INA213AIRSWR	UQFN	RSW	10	3000	203.0	203.0	35.0
INA213AIRSWT	UQFN	RSW	10	250	203.0	203.0	35.0
INA214AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
INA214AIDCKT	SC70	DCK	6	250	202.0	201.0	28.0
INA214AIRSWR	UQFN	RSW	10	3000	203.0	203.0	35.0
INA214AIRSWT	UQFN	RSW	10	250	203.0	203.0	35.0

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



4093553-4/G 01/2007

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - Falls within JEDEC MO-203 variation AB.

DCK (R-PDSO-G6)

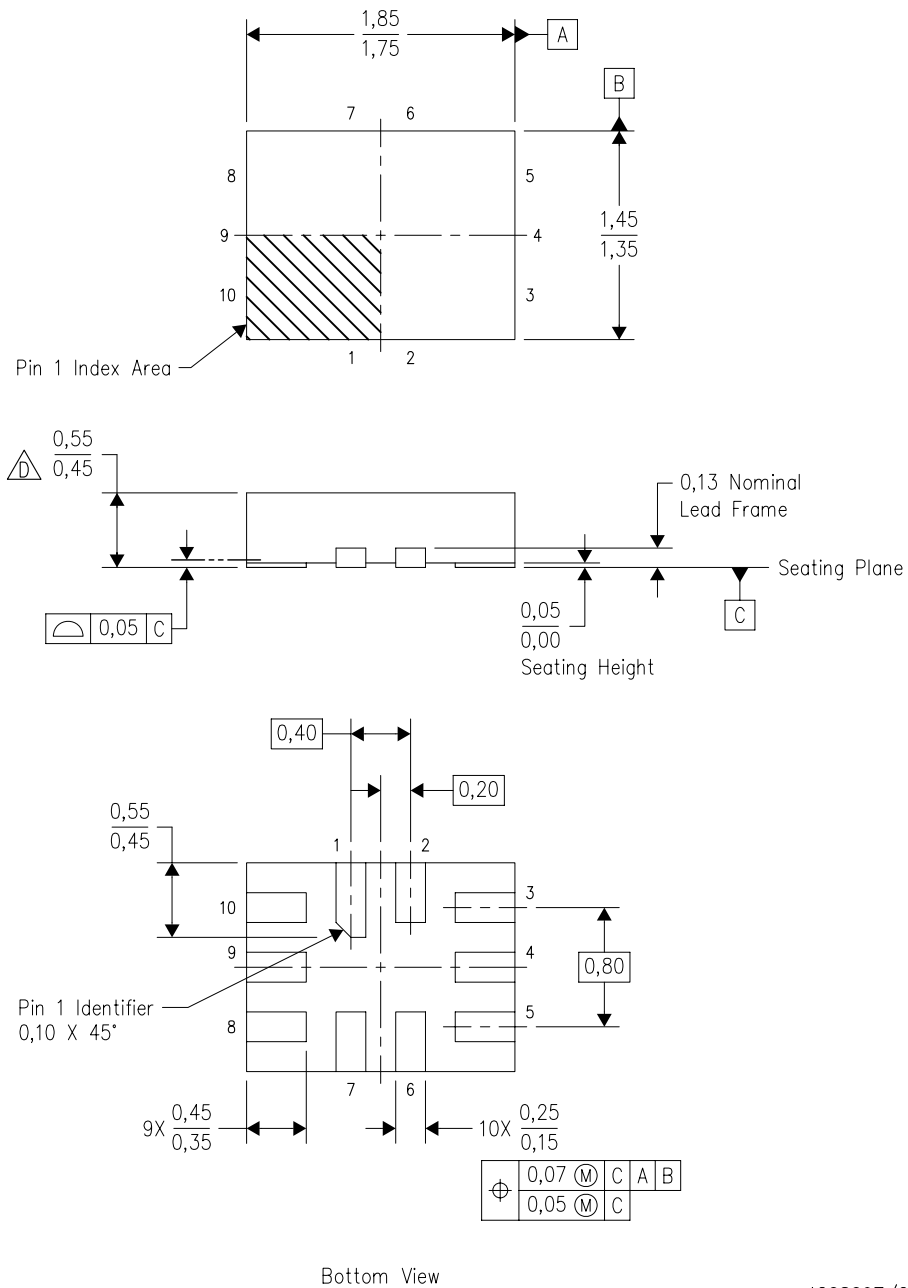
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. Publication IPC-7351 is recommended for alternate designs.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

RSW (R-PUQFN-N10)

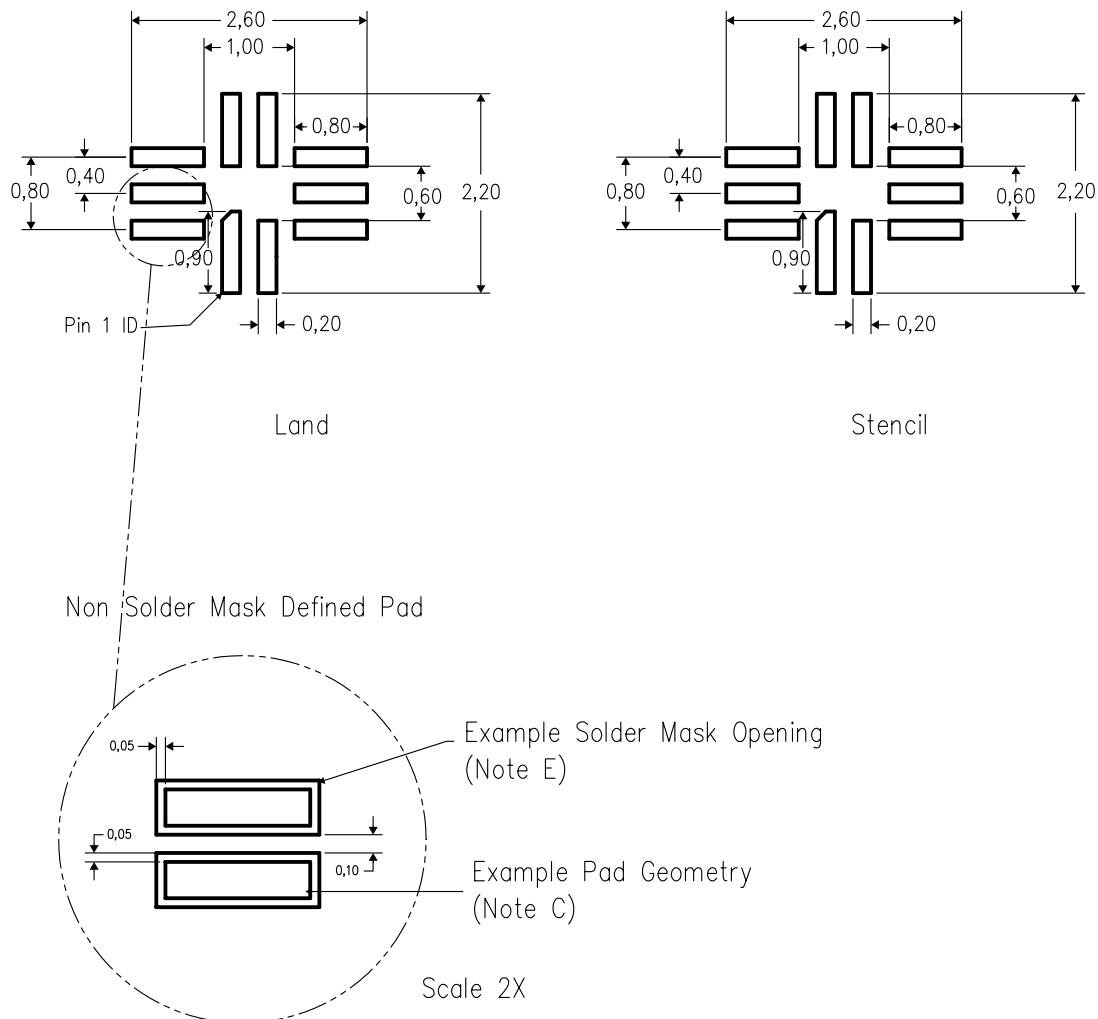
PLASTIC QUAD FLATPACK NO-LEAD



4208097/C 07/2008

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-lead) package configuration.
 - This package complies to JEDEC MO-288 variation UDEE, except minimum package height.

RSW (R-PQFP-N10)



4208245/A 10/06

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - E. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

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